Seat No.

M.Sc. (Part – I) (Semester – I) Examination, 2015 **PHYSICS (Materials Science) (New)** (Paper - I) **Mathematical Techniques**

Day and Date: Wednesday, 15-4-2015 Max. Marks: 70

Time: 11.00 a.m. to 2.00 p.m.

Instructions: 1) Q. No. 1 and Q. No. 2 are compulsory.

- 2) Answer any three questions from Q. No. 3 to Q. No. 7.
- 3) Use of Non programable calculator is allowed.
- 4) All questions carry equal marks.
- 1. a) Choose the correct alternative:
 - i) The value of the $\int_{c} \frac{dz}{z+2} c : |z| = 1$ is
 - A) $2\pi i$
- B) $-2\pi i$ C) $4\pi i$
- D) 0
- ii) Both real and imaginary parts of an analytic functions are
 - A) Harmonic

B) Non-Harmonic

C) Homomorphic

- D) Continuous
- iii) The eigen values of the matrix $\begin{pmatrix} 4 & 0 & 0 \\ 0 & 3 & 0 \\ 0 & 0 & 1 \end{pmatrix}^{-1}$ are

 - A) 4, 3, 1 B) -4, -3, -1 C) 1/4, 1/3, 1 D) 4, 3, 0

- iv) The laplace inverse of $\frac{1}{s^2 + 4}$ is

 - A) cos 2t B) $\frac{1}{2}$ cos 2t C) sin 2t D) $\frac{1}{2}$ sin 2t



			۷
v) T	he Fourier	Transform	of $e^{-x^{-/2}}$ is

- A) $e^{s^2/2}$ B) $e^{-s/2}$ C) $e^{s/2}$ D) $e^{-s^2/2}$

vi) The Fourier series of x^2 in $(-\pi, \pi)$ will involve _____ terms.

- A) only cosine terms
- B) constants
- C) both sine and cosine terms
- D) only sine terms

b) State true of false.

- i) The value of f'(z) for an analytic function f(z) = u + iv is $u_x + iv_y$.
- ii) If f (z) is analytic function and on the closed curve C, if a is any point within C, the $\frac{1}{2\pi i} \int_{C} \frac{f(z)dz}{z-a} = f(a)$.
- iii) Eigen vectors of the matrix are linearly dependent.
- iv) The Laplace transform is possible only for t > 0.
- v) The Fourier Integral of f (x) is possible only if it satisfy Dirichlet's conditions in each finite interval (-l, l) and it is integrable in $(-\infty, \infty)$.
- vi) If a, b, c, are the eigen values corresponding to the matrix A, then the eigen values corresponding to Aⁿ will be a, b, c.
- vii) A transformation is said to be linear if it satisfy T(c.x + d.y) = c.T(x) + d.T(y), where c, d are constants.
- viii) Fourier series of the function f(x) is defined only if it satisfy Dirichlet's conditions.

2. Write short notes on:

a) Write a note on Vector Spaces.

5

8

b) Define Cosine Integral and Sine Integral of the function f (x).

4

c) Find Laplace Transform of $\frac{e^{-t} \sin at}{t}$.

8



- 3. a) Use Cauchy Integral formula to evaluate $\int_C \frac{3z^2 + z}{z^2 1} dz$ where C is the circle |z-1| = 1.
 - b) Find the eigen values and eigen vectors corresponding to smallest eigen

value
$$\begin{pmatrix} 1 & 0 & -1 \\ 1 & 2 & 1 \\ 2 & 2 & 3 \end{pmatrix}$$
.

- 4. a) Solve $(D^2 5D + 6)$ y = sin 3x.
 - b) Find half range Cosine series of f(x) = x in [0, 2].
- 5. a) Find the Laplace transform of $\int_{0}^{t} ue^{-4u} \sin 5u du$.
 - b) Show that real and imaginary parts of function w = log z satisfy the Cauchy Riemann equations when z is not zero.6
- 6. a) $(x^2 D^3 3xD + 5) y = \sin(\log x)$.
 - b) Examine vectors for Linear dependence

- 7. a) Find Fourier series of $f(x) = a^2 x^2$ in [-a, a].
 - b) Find Inverse Laplace transform of $\frac{2s^2-4}{(s+1)(s-2)(s-3)}$.

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M.Sc. (Part – I) (Semester – I) Examination, 2015 MATERIALS SCIENCE (PHYSICS) (Paper – II) (New) Condensed Matter Physics

	Ce	(Paper – II) ondensed Mat	•	
Day and Date : Time : 11.00 a.				Total Marks : 70
Instructio	2) Q. (1) a 3) Attemp 4) Figures	ot five questions. and Q. (2) are co o ot any three from of to the right indi inon scientific cal	Q. 3 to Q. 7 .	
1. A) Select of	correct alternat	ive.		8
<u>-</u>	mber of atoms stal are	present in unit ar	ea of (0 1 0) plane	of simple cubic
a) 1	1/2r ²	b) 1/6r	c) 1/4r ²	d) 1/8r
2) Diff	raction of cryst	al is possible onl	y when	
a) r	nλ > 2d		b) $n\lambda < 2d$	
c) r	nλ ≤ 2d		d) $n\lambda \ge 2d$	
3) Wic	dth of energy ga	ap of supercondu	ctor at 0 K is	
a) 0)		b) 3.5 K _B Tc	
c) k	K _B Tc		d) 3.5	
4) Spe	ecific heat of sup	erconductor show	s abrupt change at	the temperature $T =$
a) 0)	b) <t<sub>c</t<sub>	c) >T _c	d) = Tc
•	cical current (I) o		y with increase of	applied magnetic
a) V	Veiss's		b) Silsbee's	
c) L	orentz		d) Hunt's	



6) Penetration depth (λ) is the value of 'x' for which flux density reduces of its original value.			density reduces to				
		a)	1/e	b) infinite	c) o	d) e	
	7)			age dipole energy t n is said to be effec	o average thermal e ctive.	energy is	
		a)	1	b) <1	c) >1	d) -1	
	8)	Fe	ermi level in ca	se of n-type semi	conductor lies at		
		a)	$E_F = \frac{E_C + E_D}{2}$		b) $E_F = \frac{E_C - E_D}{2}$		
		c)	$=\frac{E_V-E_D}{2}$		d) $E_F = \frac{E_V + E_D}{2}$		
	B) Sta	ate	true or false.				6
	1)	Se	emiconductor l	have positive temp	erature coefficient	of resistance.	
	2)	At	Curie tempera	ature materials sho	ows normal to supe	erconducting state.	
	3)	Si	mple cubic un	it cell having atom	ic radius $r = a/2$.		
	4)	FC	CC structure c	ontains the contrib	oution of six atoms.		
	5)	E	ktrinsic semico	onductor contains	equal number of h	oles and electrons.	
	6)	Tł	ne reverse sati	uration current in s	silicon diode is nea	rly 1 nA.	
2.	Attem	pt f	ollowing.				14
	1) Or	ient	tational polariz	ation			5
	2) Ab	ser	nce of fivefold	symmetry			5
	3) Co	ope	er pair				4
3.	a) Wh	nat	is supercondu	ctor? Discuss Lor	ndon theory in deta	il.	10
	b) Ex	pla	in Meissner's	effect.			4



4.	a)	 a) What is dielectric polarization? Give the expression for electronic polarizability. 		
	b)	Calculate the electronic polarizability of an isolated Se atom.		
		The atomic radius of Se atom is 0.12 nm.	4	
5.	a)	Derive rectifier equation.	10	
	b)	Write the relation for Fermi level in n-type semiconductor.	4	
6.	a)	Write in detail about calculation of energy gap in intrinsic semiconductor.	10	
	b)	Calculate critical current (I_c) flowing through long superconducting wire of diameter 10^{-3} m in the absence of applied field. Given Hc = 7.9×10^3 A/m.	4	
7.	a)	Explain the behaviour of free electron in periodic potential.	8	
	b)	Write about the formation of number of possible states in a band.	6	

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M.Sc. (Part – I) (Semester – I) Examination, 2015 PHYSICS (Mat. Sci.) (New) Analog and Digital Electronics (Paper – III)

Day and Date: Monday, 20-4-2015 Total Marks: 70

Time: 11.00 a.m. to 2.00 p.m.

Instructions: 1) Q. 1 and 2 are compulsory.

- 2) Answer any three questions from Q. 3 to Q. 7.
- 3) All questions carry equal marks.
- 1. Objective questions:

14

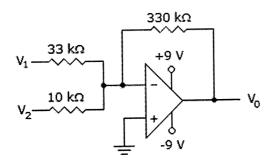
a) Select correct alternatives:

6

- 1) An ideal op-amp has
 - a) Infinite output impedance
- b) Infinite band width
- c) Zero input impedance
- d) All of the above
- 2) Another name of the unity gain amplifier is
 - a) Differential amplifier
- b) Non-inverting amplifier

c) Comparator

- d) Voltage follower
- 3) Calculate the output voltage of the following circuit if $V_1 = -0.2 \text{ V}$ and $V_2 = 0 \text{ V}$.



a) 0 V

b) -6.6 V

c) - 4 V

d) 2 V

2.

3.



4)	4) How many Flip-Flops are required for mod – 16 counter?				
	a) 5	b) 6			
	c) 3	d) 4			
5)	The device which changes from serial	data to parallel data is			
	a) Counter	b) Multiplexer			
	c) Demultiplexer	d) Flip-flop			
6)	Addressing in which the instructions co the operated on is known as	ontains the address of the data to			
	a) Immediate addressing	b) Implied addressing			
	c) Register addressing	d) Direct addressing			
b) Stat	te true or false /Justify/ one line answer	:	8		
1)	The gain of the non-inverting amplifier i	s			
2)	An astable multivibrator is also known	as a			
3)	What is the resonant frequency equation	on of Wien bridge oscillator?			
4)	The circuit for a DEMUX is basically the the decoder has an enable input.	e same as for a decoder, provided			
5)	The memory used in synchronous seq	uential circuits are flip-flops.			
6)	Design NOT gate using 1×2 demux?				
7)	Program counter is a bit r	egister.			
8)	Trap is a maskable interrupt.				
Write s	short notes on :		14		
a) Ins	trumentation Amplifier.		5		
b) We	ein bridge oscillator.		5		
c) Mu	Itiplication program for two 8-bit numbe	rs in 8085 μp.	4		
a) Usii	ng inverting configuration of an op-amp	explain i) summing amplifier			
,	caling amplifier and iii) averaging ampli		10		
•	b) Write down the circuit diagram for constant current bias.				



4.	a)	Explain in detail about voltage regulators with neat sketches.	8
	b)	Write a brief note on Astable Multivibrator.	6
5.	a)	State Demorgan Theorems with examples.	8
	b)	Explain about the Working of RS flip-flop.	6
6.	a)	What do you mean by flip-flops? Describe the edge triggered flip-flops. Convert SR flip-flops into JK flip-flops.	8
	b)	Draw and explain the working of 4-bit up and down synchronous counter. Also describe the working of shift register.	6
7.	a)	Explain in detail about the Architectural features of 8085 microprocessor with the help of neat diagrams.	8
	b)	What is an addressing mode? Write about the addressing modes of 8085 microprocessor with examples.	6



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M.Sc. (Part – I) (Semester – I) Examination, 2015 PHYSICS (Materials Science) Paper No. – IV: Classical Mechanics (New)

Day and Date: Wednesday, 22-4-2015 Total Marks: 70

Time: 11.00 a.m. to 2.00 p.m.

Instructions: 1) Q. (1) and (2) are compulsory.

- 2) Answer any three questions from Q. 3 to Q. 7.
- 3) All questions carry equal marks.
- 1. Objective questions:

14

a) Choose correct alternative:

8

1) A bead is constrained to slide on a frictionless rod that is fixed at an angle θ with a vertical axis and is rotating with angular frequency ω about the axis. Taking the distance s along the rod as a variable, the Lagrangian for the bead is equal to

a)
$$\frac{1}{2}$$
 ms² - mgs cos θ

b)
$$\frac{1}{2}$$
ms² + $\frac{1}{2}$ m (ω s cos θ)² + mgs cos θ

c)
$$\frac{1}{2}$$
 ms² + mgs cos θ

d)
$$\frac{1}{2}$$
ms² + $\frac{1}{2}$ m (ω s sin θ)² - mgs cos θ

- 2) A particle of mass m moves in a 1 D potential $V(x) = -ax^2 + bx^4$, where a and b are positive constants. The angular frequency of small oscillations about the minima of the potential is equal to
 - a) $\pi (a/m)^{\frac{1}{2}}$

b) $(a/mb)^{\frac{1}{2}}$

c) $2(a/m)^{\frac{1}{2}}$

d) $(a/2m)^{\frac{1}{2}}$



- 3) The curvature of Mars is such that its surface drops a vertical distance of 2.0 m for every 3600 m tangent to the surface. In addition, the gravitational acceleration near its surface is 0.4 times that near the surface of earth. What is the speed of the golf ball would need to orbit Mars near the surface, ignoring the effects of air resistance? (Radius of Mars $\sim 8 \times 10^6$ m).
 - a) 0.9 km/s

b) 1.8 km/s

c) 3.6 km/s

d) 4.5 km/s

- 4) A sphere of mass m is released from rest in a stationary viscous medium. In addition to the gravitational force of magnitude mg, the sphere experiences a retarding force of magnitude bv, where v is the speed of the sphere and b is a constant. Assume that the buoyant force is negligible. Which of the following statements about the sphere is true?
 - a) Its KE decreases due to retarding force
 - b) Its KE increases to maximum and decreases to zero due to retarding force
 - c) Its speed increases monotonically, approaching a terminal speed that depends on b but not on m
 - d) Its speed increases monotonically, approaching a terminal speed that depends on both b and m
- 5) A man of mass m on an initially stationary boat gets off the boat by leaping to the left in an exactly horizontal direction. Immediately after the leap, the boat of mass M, is observed to be moving to the right at speed v. How much work did the man do during the leap (both on his body and on the boat)?

a)
$$\frac{1}{2}$$
Mv²

b)
$$\frac{1}{2}$$
mv²

c)
$$\frac{1}{2}(m+M)v^2$$

$$d) \frac{1}{2} \left(M + \frac{M^2}{m} \right) v^2$$

6) A particle of unit mass undergoes 1-D motion such that its velocity varies according to $v(x) = \beta x^{-n}$, where β and n are constant and x is the position of the particle. What is the acceleration of the particle as a function of x?

a)
$$-n\beta^2 x^{-2n-1}$$

b)
$$-n\beta^2 x^{-n-1}$$

c)
$$-n\beta^2x^{-n}$$

6

4



b)

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7) A ball is dropped from a 80 % of what it was just height of most nearly	a height h. As it bounces on the state of th	· •
a) 0.94 h	b) 0.80 h	
c) 0.75 h	d) 0.64 h	
8) The term monogenic inc	dicates all forces are	
 a) generated from a single of position coordinate 	• " ,	potential is an explit function
b) generated from a single of position and time of	· · · · ·	potential is an explit function
c) generated from a mul of position coordinat		d potential is an explit function
d) none of the above		
True/false:		6
 Stationary value for a line path has the same value neighborings paths. 	ne integral mean that the i e to within 1 st order infinite	
2) Number of Generalized freedom.	coordinates are greater tha	an number of degrees of

- 3) Poisson Bracket are invariant under canonical transformations.
- 4) Holonomic constraints cannot be expressed as an algebraic equation.
- 5) In any virtual displacement, the total work done by the forces of constraint vanish, unless of course the constraint is associated with frictional forces.
- 6) If the system is invariant under translation along a given direction then corresponding linear momentum is conserved.
- 2. Write short answer: 14 a) Show that the Newton's laws are invariant under Galilean transformation. 5 b) Explain the motion of Gyroscope. 5
 - c) Show that the total linear momentum of the system as measured from centre of mass coordinate system is zero.



3.	a)	Derive Lagrange's equation of motion for a partly conservative system.	10
	b)	What is Hamiltonian (H) ? Discuss.	4
4.	a)	Obtain Euler – Lagrange differential equation.	8
	b)	Write a note on variational principle.	6
5.	a)	What is Canonical transformations? Explain in detail what conditions a transformation can satisfied to be called canonical transformation.	8
	b)	Show that $P = \frac{1}{2} (p^2 + q^2)$ and $Q = \tan^{-1} q/p$ is a canonical.	6
6.	a)	State and explain Kepler's laws of planetary motion. Derive 2 nd Kepler's law.	8
	b)	Discuss principle of least action.	6
7.	a)	Show that Poisson bracket are invariant under canonical transformations.	8
	b)	What are constraints? State and explain all types of constraints with one example of each case.	6

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M.Sc. (Part – I) (Semester – I) Examination, 2015 PHYSICS (Materials Science) Paper No. – I: Mathematical Techniques (Old)

Day and Date: Wednesday, 15-4-2015 Total Marks: 70

Time: 11.00 a.m. to 2.00 p.m.

Instructions: 1) Question No. 1 and 2 are compulsory.

- 2) Answer any three questions from Question No. 3 to 7.
- 3) All questions carry equal marks.
- 1. A) Choose the most correct alternative:

6

- 1) xy'' (2x 1)y' + (x 1)y = 0 for this differential equation consider the statements (i) it is linear (ii) of second degree, then
 - a) only (i) is true
 - b) only (ii) is true
 - c) both (i) and (ii) are true
 - d) both (i) and (ii) are false
- 2) The trace of the matrix $A = \begin{bmatrix} 2 & 4 \\ 3 & 7 \end{bmatrix}$ is
 - a) -7
- b) 9
- c) 2
- d) 14
- 3) The function $f(z) = \frac{z^2 3z + 4}{z 3}$ has a simple pole at $Z = \underline{\qquad}$
 - a) ∞
- b) 3
- c) 1
- d) 2
- 4) For a square matrix, conjugate transpose of which coincide with the matrix itself is called
 - a) Unitary

b) Hermitian

c) Orthogonal

d) Skew Hermitian



- 5) For a function to have Fourier series expansion necessary conditions are
 - a) f(x) and its integrals are finite
 - b) f(x) and its integrals are single valued
 - c) f(x) has discontinuities finite in nature and number
 - d) all the above
- 6) Laplace Transform of the function f(t) = sinh2t is = _____

- a) $\frac{s}{s^2+2}$ b) $\frac{2}{s^2+4}$ c) $\frac{2}{s^2-4}$ d) $\frac{s}{s^2-4}$

8

B) State True or False:

- 1) The Laplace's transform of f(t) = t is $1/S^2$.
- 2) The Eigen values of Hermitian matrix are real.
- 3) Inverse Laplace Transform of $\frac{3}{(s-2)^2}$ is $\frac{1}{3}e^{-2t}t$.
- 4) $\begin{bmatrix} 3 & 9 \\ -2 & 6 \end{bmatrix}$ is a singular matrix.
- 5) $f(z) = \frac{\sin z}{z^4}$ has a pole of order 4 at z = 0.
- 6) $AA^T = I$ then A is said to be orthogonal.
- 7) The differential equation $(x^2 4xy 2y^2) dx + (y^2 4xy 2x^2) dy = 0$ is not an exact differential equation.
- 8) Term by term integration of a convergent Fourier series is not valid.
- 2. Attempt the following:
 - a) Show that $A = \begin{bmatrix} -3 & 2 \\ -2 & 1 \end{bmatrix}$ is not diagonalizable.
 - b) Define a pole. Find the pole and its order for $f(z) = \frac{\sin z}{z^4}$.
 - c) Define Laplace transform. Derive Laplace Transform of the functions

(i)
$$f(t) = e^{at}$$
 (ii) $f(t) = \sin at$.

(5+5+4)



- 3. a) Using Residue Theorem evaluate $\int_0^{2\pi} \frac{d\theta}{5 + 4\cos\theta}$.
 - b) Find Eigen values and corresponding Eigen vectors for the matrix.

$$A = \begin{bmatrix} 3 & 4 & -6 \\ 4 & 3 & -6 \\ -6 & -6 & -14 \end{bmatrix}$$
 (6+8)

- 4. a) Find a matrix S that diagonalizes $A = \begin{bmatrix} 3 & -2 & 0 \\ -2 & 3 & 0 \\ 0 & 0 & 5 \end{bmatrix}$.
 - b) Solve:

i)
$$\frac{d^2y}{dx^2} + 9y = x \sin x$$

- ii) Find the solution of $\frac{d^2y}{dx^2} + y = 0$, satisfying y(0) = 1 and $y(\frac{\pi}{2}) = 2$. (8+6)
- 5. a) Expand the function $f(x) = \sin x$ for $0 \le x \le \pi$.

 $f(x) = -\sin x$ for $-\pi \le x \le 0$ in Fourier series and draw the waveform.

b) Find the Fourier transform F(K) of the Gaussian distribution function

$$f(t) = N e^{-at^2}$$
 where N and 'a' are constants. (8+6)

- 6. a) Obtain Laplace Transform of $\frac{d^2y}{dt^2} + 3\frac{dy}{dt} + 4y + 2\int_0^t y(t) dt$
 - b) Using Partial fractions find Inverse Laplace Transform of

i)
$$\frac{21s-33}{(s+1)(s-2)^3}$$

- ii) Find Inverse Laplace transform of $\frac{2s+1}{s(s+1)}$. (6+8)
- 7. a) Express general form of first order ODE and solution y(t). What do you mean by boundary conditions? Thus explain Euler's method to numerically solve the ODE.
 - b) Classify the singularities and calculate residue for $f(z) = \frac{1}{z^2 1}$. (10+4)

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M.Sc. (Part – I) (Semester – I) Examination, 2015 PHYSICS (Material Science) (Old) (Paper – II) Condensed Matter Physics

Day and Date : Friday, 17-4-2015 Total Marks : 70

Time: 11.00 a.m. to 2.00 p.m.

Instructions: 1) Questions 1 and 2 are compulsory.

2) Answer any three questions from Q. 3 to Q. 7.

3) All questions carry equal marks.

1. a) Choose the correct alternative.

1) The distribution of electrons in the conduction band is given by

- i) (density of quantum states) × (energy of a state)
- ii) (density of quantum states) × (probability a state is occupied)
- iii) (energy of quantum states) × (probability a state is occupied)
- iv) (energy of quantum states) × (chemical potential of a state)
- 2) A plane intercepts at (a, b/2, 3c) in a simple cubic unit cell. The Miller indices of the plane are
 - i) [1 3 2]

ii) [2 6 1]

iii) [3 6 1]

iv) [1 2 3]

- 3) A beam of X-ray of wavelength 0.25 nm is incident on a crystal of interplanar separation 0.30 nm. The glancing angle for first order diffraction is
 - i) 24.6°

ii) 36.0°

iii) 56.4°

iv) 54.8°

- 4) The nearest neighbour distance in the case of bcc structure is
 - i) $\frac{a\sqrt{3}}{2}$

ii) $\frac{a}{\sqrt{2}}$

iii) $\frac{2a}{\sqrt{3}}$

iv) $\sqrt{2}a$



5)	The order of magnitude of the	enei	rgy gap of a typical superconductor is	
	i) 1 MeV	ii)	1 KeV	
	iii) 1 eV	iv)	1 meV	
6)	The equation of motion of eac influence of a static electric fie		lectron in the Fermi surface under the is	
	i) $\hbar \frac{dK}{dt} = Ee$	ii)	$\hbar \frac{dK}{dt} = \frac{E}{e}$	
	iii) $\hbar \frac{dK}{dt} = Ee^2$	iv)	$\hbar \frac{dK}{dt} = \frac{e}{E}$	
7)	Meissner effect implies that in magnetic susceptibility equal to		perconducting state, a material has a	
	i) $\chi = 0$	ii)	$\chi = -1$	
	iii) $\chi = 1$	iv)	$\chi = \infty$	
8)	A lattice is characterized by fol	low	ing primitive vectors	
	$\vec{a} = 2(\hat{i} + \hat{j}), \vec{b} = 2(\vec{j} + \hat{k}), \vec{c} = 2(\hat{k})$ to this lattice is i) bcc with cube edge π ii) bcc with cube edge 2π iii) fcc with cube edge π iv) fcc with cube edge 2π	: + î)	. The reciprocal lattice corresponding	
b) Fi	ll in the gaps with appropriate wo	ord.		6
i)	For a given dielectric, the electric by temperature change.	roni	c polarizability $\left(\alpha_{_{\mathrm{e}}}\right)$ is	
ii)	The depletion region in an oper	n cir	cuited p-n junction contains	
iii)	The width of the energy gap of	a sı	uperconductor at 0 K is about	
iv)	The number of ions in the unit of	cell	of CsCl crystal is	
v)	The Miller indices of the plane pa	ıralle	el to y and z axes are	
vi)	Relative permeability of a med	diun	n is the permeability relative to that of	

2.	a)	Attempt any two of the followings:	8
		i) Explain direct and indirect band gaps in semiconductors.	
		ii) Show that the polarizability (α) of a conducting metallic sphere of radius 'a' is $\alpha = a^3$.	
		iii) What is the dipole theory of Ferro electricity?	
	b)	Attempt any one of the followings:	6
		 i) What is Meissner effect? Obtain an expression for the London penetration depth of magnetic field for a superconductor. 	
		ii) A magnetic material has a magnetization of 3300 A/m and flux density of 0.0044 Wb/m ² . Calculate the magnetizing force and the relative permeability of a material.	
3.	a)	Write short notes on the followings:	8
		i) Reciprocal lattice	
		ii) Metal-semiconductor contacts.	
	b)	What are intrinsic and extrinsic semiconductors? Discuss the location of Fermi levels under suitable limiting conditions and give the necessary theory.	6
4.	a)	Explain electronic polarization in atoms and obtain an expression for electronic polarizability in terms of the radius of atom.	8
	b)	Explain qualitatively how p-n junction functions as a rectifier.	6
5.	a)	Derive the susceptibility expression for ferromagnetic material.	8
	b)	Write a note on ionic polarizability.	6
6.	a)	What is effective mass? Give the expression for the effective mass of an electron.	8
	b)	In an n-type semiconductor, the Fermi level lies 0.3 eV below the conduction band at 300 K. If the temperature is increased to 330 K, find the new position of the Fermi level.	6
7.	a)	Explain Type I and Type II superconductors.	6
	-	Briefly explain the BCS theory of superconductivity and describe one experimental evidence for the existence of energy gap.	8

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M.Sc. (Part – I) (Semester – I) Examination, 2015 PHYSICS (Materials Science) (Paper – III) Analog and Digital Electronics (Old)

	Analog and Digit	tal Electronics (O	ld)	
_	Monday, 20-4-2015 m. to 2.00 p.m.		Total Marks :	: 70
Instr	,	are compulsory . t hree from Q. 3 to Q. e right indicate full n		
1. a) Select of	correct alternatives :			14
1) A dif circu	ferentiator has uit.	_ in the input termina	l, for an opamp based	8
-	Capacitor Resistance	b) Inductord) None of these		
a) M c) B	iplexer means Many I/P's into one O/P Both a and b 4150 is	b) One I/P into m	-	
a) 1	6:1 MUX :16 DMUX	b) 8:1 MUX d) 1:8 DMUX		
	logic gate repres			
	4-bit adder circuit can be des adder circuits.	signed using one half a	adder and	
a) 3	b) 4	c) 5	d) 7	
•	Oscillator circuit Phase shift Hartley	t uses Inductive feed b) Wien bridge d) Colpit	back.	



		cird a) c) Ou	cuit. Res Cap	sistan pacito timpe	ce r	e of	IC 74 ⁻ 1000		b) d) oicall	Induc None	tor of the	se			np base	d	
	b) Fi	ill in t	the I	blank	s/Sta	te tr	ue or	False	:								6
	i)) The	e nu	mber	of flip	flops	s requi	red to	desig	n MO	D 10 c	ounte	eris_				
	ii)) In 8	3085	5, Op	code [·]	fetch	n cycle	e is			sta	ted.					
	iii)) SR	flip	flop c	loes r	not a	ccept	the in	put e	ntry w	hen_						
	iv) Col	lpit (oscilla	ator c	ircui	it uses	tapp	ed ind	ductiv	e feed	back					
	V)) Ou	tput	impe	edanc	e of	IC 74	1 is ty	pical	ly 10 s	Ω .						
	vi)) In 8	308	5, ALF	Esigr	nal is	sused	to de	multi	olex a	ddres	s/data	a bus	3.			
2.	Atter	npt fo	ollo	wing :													14
	1) A	ddre	ssin	ıg mo	des o	f 808	85 mic	cropro	cess	or.							5
	2) Fi	ixed	volt	age re	egula	tors.	ı										5
	3) O	pam	p as	an Ir	ntegra	ator.											4
3.	•	•		verting ing an		_	ation v	with 3-	input	s can	be use	ed as	a suı	mmin	g scalin	g	8
	b) IC	741	Op	amp	confi	gure	ed in in	vertin	g mo	de wi	th R ₁ :	= 1k a	and F	$R_{F} = 1$	10K.		
	Fi	ind	1)	Exac	ct clos	sed I	loop ga	ain									
			2)	Idea	clos	ed lo	oop ga	in.									6
4.		raw a scilla			in ph	ase	shift o	scillat	or, ok	tain a	ın exp	ressi	on fo	r freq	luency (of	8
				phase oltage			illator).	for f ₀	= 1 k	(Hz, u	ısing I	C741					6

-3-

5.	a)	Describe architecture of Intel 8085 microprocessor.	8
	b)	Explain demultiplexing of AD7-AD0 signals.	6
6.	a)	What is shift register? Draw and explain logic diagram of PISO shift register.	8
	b)	Draw and explain 8:1 multiplexer using AND gate.	6
7.	a)	Write an ALP for addition of two 8 bit numbers using immediate addressing mode.	8
	b)	Reduce the following logical expressions using Boolean laws:	
		$(A\overline{B} + AB)(\overline{A}BC + ABC)$.	6



Seat	
No.	

M.Sc. (Part – I) (Semester – I) Examination, 2015 PHYSICS (Materials Science) (Paper – IV) (Old) Analytical Techniques – I

		•	•		
Day and Da	ate: Wednesday, 2	2-4-2015		Total Marks :	: 70
Time : 11.0	00 a.m. to 2.00 p.m				
Instru		ot five questions. and (2) are comp ot any three from			
					14
1. a) Sel	ect correct alterna	tives :			8
1)	The range of visibl	e spectra extends	sover		
į	a) 400 nm to 800 r	nm	b) 200 nm to 800	nm	
	c) 200 nm to 400 r	nm	d) 150 nm to 200 nm		
•	According to Lamb		ensity of the input l	beam falls to 0.369	
;	a) 1 cm	b) (1/K) cm	c) K cm	d) None above	
3)	The law that relate	s to the absorptio	n due to solution is	S	
i	a) Beer's law		b) Lambert's law		
	c) Ferries law		d) Both a and b		
4)	The following trans	sition is a forbiddo	ned transition		
	a) $n-\pi^*$	b) $\pi - \pi^*$	c) $\pi - \sigma^*$	d) $\sigma - \sigma^*$	
5)	The ascending ord	ler of energy is as	below		
;	a) σ , π , π^* , σ^*	b) $\sigma, \pi^*, \pi, \sigma^*$	c) π , σ , π^* , σ^*	d) π^* , σ , π , σ^*	
6) l	Following is not an	auxochrome			
i	a) -OH	b) -OR	c) - NH ₂	d) C = C	



	') The conjugation causes					
	a) Increase in energy of HOMO b) Decrease in energy LOMC					
	c) Increase in λ_{max} d) All above					
	a) NaCl b) Glass c) Quartz d) Plastic					
b)	Fill in the blanks/State True or False :	6				
) Number of NMR signals for CH ₃ – OH is					
	2) The molecular formula for a ketone is					
	3) The finger print region extends between the λ =					
	In case of nonlinear molecular the vibrational degrees of freedom are $3n-3-2=3n-5$.					
	i) The chromophores are radicals which cause absorption of visible radiation intensities.					
	3) The energy of stretching vibrations is greater than the bending vibrations.					
Wr	e a short note on :	14				
		5				
•		5				
-		4				
3)	basic principle of 1 E3.	4				
a)	Describe basic instrumentation setup for UV-VIS spectro photometer.					
b)	Explain sources of UV and VIS radiations.	6				
a)	Draw and explain instrumentation of IR spectrometer.					
b)	Give difference between optics for UV-vis and IR spectrometers.	6				
a)	Describe basic principle of NMR spectroscopy.	8				
b)	Explain mechanism of absorption of magnetic field and transitions in case of					
	IMR spectroscopy.	6				
a)	Describe instrumentation of mass spectrometer.	8				
b)	Explain basic concept of mass spectroscopy.	6				
a)	Explain basic principle of AAS.	6				
	Describe instrumentation setup for AAS.	8				
	b) F 1 2 3 4 5 6 Writ 1) L 2) G 3 b) E a) D 5 b) E b)	 a) Increase in energy of HOMO b) Decrease in energy LOMC c) Increase in λ_{max} d) All above 8) Following crystal could be used as optical component is case of the IR spectrometer a) NaCl b) Glass c) Quartz d) Plastic b) Fill in the blanks/State True or False: 1) Number of NMR signals for CH₃ – OH is 2) The molecular formula for a ketone is 3) The finger print region extends between the λ = 4) In case of nonlinear molecular the vibrational degrees of freedom are 3n – 3 – 2 = 3n – 5. 5) The chromophores are radicals which cause absorption of visible radiation 				

Seat	
No.	

IVI.SC.	PHYSICS (Materia Paper – V : Stati	ıls Science) (N	ew)	
Day and Date: Thurs Time: 11.00 a.m. to 2	-		Total Marks : 7	70
Instructions	 Q. 1 and Q. 2 are 0 Attempt any three All questions carry Figures to the right 	e from Q. 3 to Q. 7 y equal marks.		
1. A) Choose the co	orrect alternatives :			8
i) The entro	py (S) of the system ha	aving Ω (E) access	sible states is given by	
a) k ln Ω	(E)	b) Nk InΩ (E)	
c) kT ln (2 (E)	d) None of th	iese	
ii) The mean T is	energy for a classical c	one dimensional os	scillator at temperature	
a) kT	b) $\frac{kT}{2}$	c) $\frac{3kT}{2}$	d) 3kT	
	on function of a single on non-interacting gas m	•	. The partition function given by	
a) $\frac{(Z_{\alpha})^N}{N!}$	b) $(Z_{\alpha})^{N}$	c) N Z_{α}	d) $\frac{(Z_{\alpha})^N}{N}$	
	of mass 'm' and total e rmonic motion. Its traje		uting one dimensional ace is	
a) circle	b) ellipse	c) parabola	d) hyperbola	
, , ,	sical parameters which canonical ensemble a		in a system of interest	
a) E, V, T	b) N, T, μ	c) N, V, E	d) None of these	



- vi) A system consists of three independent particles localized in space. Each particle has two states of energy 0 and ϵ . When this system is in thermal equilibrium with a heat bath at temperature T, its partition function is given by a) $(1+e^{-\beta\epsilon})^3$ b) $(1+3e^{-\beta\epsilon})$ c) $(1+e^{-\beta\epsilon})$ d) None of these
- vii) Internal energy (\overline{E}) of a system is given by
 - a) $-\frac{\partial}{\partial \beta} \ln Z|_{V,N}$

b) $\frac{\partial}{\partial \beta} \ln Z|_{V,N}$

c) $-\beta \frac{\partial}{\partial T} \ln Z|_{V,N}$

- d) None of these
- viii) If the volume of the perfect gas of N atoms is doubled then the change in the entropy is
 - a) zero
- b) Nk In 2
- c) 2Nk
- d) none of these

B) Fill in the blanks / state **true** or **false**:

6

- i) Canonical ensemble is related to _____ equilibrium of system.
- ii) Plank's radiation law can be derived by using _____ statistic.
- iii) Fermi energy gives the value of energy in Fermi Dirac system upto which all the energy states are _____
- iv) Bose Einstein statistics is not applicable to photons and symmetric particles. (True/False).
- v) The partition function represents the number of thermally accessible energy levels at a given temperature. (True/False).
- vi) Equipartition theorem is a classical theorem that states that every degree of freedom for motion has an energy of $\frac{1}{2}k_BT$. (True/False).
- 2. Attempt any three of the followings:

- a) Show that 1D harmonic oscillator executes elliptical motion.
- b) Distinguish between different ensembles.
- c) Explain Triple point.
- d) Distinguish between 1st order and 2nd order phase transitions.

		-3-	SLR-HP – 38	81
3.	Answer the followings: a) Explain Bose-Einstein statis b) Write the condition for ideal			4 10
4.	Answer the followings: a) Write the condition for Boseb) What is the Gibb's paradox '			8
5.	Answer the followings: a) Write the Clausius-Clapeyro b) Write Ehrenfest's equations	•	•	8
6.	Answer the followings:a) Show that average energy of Fermi energy of the system.b) Explain Maxwell. Boltzmann		_	10 4
7.	Answer the followings:a) Write the Liouville's theoremb) Write the expression for total using grand canonical partition	al number of particles (N		10 4

Seat	
No.	

M.Sc. (Part – I) (Semester – II) Examination, 2015 PHYSICS (Mat.Sci.)

Paper - VI: Quantum Mechanics (New)

Day and Date: Saturday, 18-4-2015 Max. Marks: 70

Time: 11.00 a.m. to 2.00 p.m.

Instructions: 1) Q. (1) and Q (2) are compulsory.

2) Attempt any three questions from Q. (3) to Q. (7).

3) All questions carry equal marks.

4) Figures to the **right** indicate marks.

1. A) Choose the correct alternative:

14

i) According to Schrödinger a particle is equivalent to a

6

a) single wave

b) light wave

c) wave packet

- d) sound wave
- ii) The wave function of a particle in a box of length L is

$$\psi(x) = \sqrt{\frac{2}{L}} \sin\left(\frac{\pi x}{L}\right) \qquad 0 < x < L$$

$$\psi(x) = 0 \quad \text{for} \quad x < 0 \quad \text{and} \quad x > L \ .$$

The probability of finding it in the region $0 < x < \frac{L}{2}$ is

- a) 0.4%
- b) 0.3 %
- c) 0.2 % d) 0.5 %
- iii) In case of a wave function $\psi = \frac{e^{ikr}}{r}$, the probability current density is
- a) $\frac{V}{r^2}$ b) $\frac{V}{r}$ c) $\frac{V}{r^3}$
- d) v

iv) If proton and electron have same De-Broglie wavelength 2A° then



		a) both have sam	ne kinetic energy	/		
		b) both have sam	ne velocity			
		c) both have sam	e momentum			
		d) Kinetic energy	of proton is mo	re than K.E. o	f an electron	
	v)	The degeneracy	of hydrogen atoi	m in state n =	3 is	
		a) 3	b) 5	c) 6	d) 9	
	vi)	A system is know	n to be in a state	e described b	y the wave function	
		$\psi(\theta,\phi) = \frac{1}{\sqrt{30}} \Big[5Y_4^0$	$+Y_6^0+2Y_6^3$ whe	ere, Y_l^m are the	e spherical Harmonic	S,
		the probability of	finding the syste	em in a state v	with $m = 0$ is	
		a) 0	b) $\frac{2}{15}$	c) $\frac{1}{4}$	d) $\frac{13}{15}$	
	B) Wr	ite true or false :				4
	vii)	The experimental	proof of wave p	article duality	was given by Thomps	son.
	viii)	Hermitian operato	or has imaginary	eigen values		
	ix)	The graph of a wa	ave function aga	inst r for hydr	ogen for I = 0 state sh	ows
	x)	The experimental	ground state en	ergy of the He	elium atom is (– 79.00	ev).
	C) Fill	in the blanks :				4
	xi)	The M shell can a	ccommodate	(electrons.	
	xii)	The selection rule	for Harmonic o	scillator is		
	xiii)	The Bohr magneto	on is			
	xiv)	±1 eigenvalues b	elong to an	op	erator.	
2.	Answe	er any 3 in brief :				14
	a) Usi	ing proper operato	rs derive ore dim	nensional Sch	rödinger equation.	
		nere exists a set of operators A and E		•	h are eigen functions te.	of

c) Write the formula for Normalized wave function of Hydrogen for radial part

d) Write a note on Hiesenberg's uncertainty principle.

and explain it.



3.	a)	Distinguish between Hermitian and unitary operators.	3
	b)	Discuss the problem of one dimensional box of width a comment on the graphs showing energy levels and corresponding eigen functions.	7
	c)	What are the factors which influence the wavelengths of different transitions in an energy spectrum of a box ?	4
4.	a)	Discuss the Harmonic oscillator problem. Calculate the energy eigen value and normalized energy eigen functions.	10
	b)	Calculate first few Hermite polynomials upto H_3 and prove H_3 = 2 and H_2 – 4 H_1 .	4
5.	a)	Solve the radial wave equation for hydrogen like atom.	10
	b)	Obtain an expression for the probability density of 1s orbital.	4
6.	a)	In many electron atoms how the electrons of larger 'l' values reduce the effective charge on the nucleus? State Slater's rules and hence calculate the effective charge on Nitrogen nuclei.	10
	b)	Explain what is Plater determinant.	4
7.	a)	Discuss the Hydrogen molecule ion problem using a proper Hamiltonian Normalized molecular orbitals. Calculate the $\rm H_{aa}$ and $\rm H_{ab}$ type integrals and calculate energies.	10
	b)	What are normalized wave functions? Evaluate the ground state energy.	4



Seat	
No.	

M.Sc. – I (Semester – II) Examination, 2015 PHYSICS (Materials Science)

Paper - VII: Electrodynamics (New)

	i apci	VIII . LICOTIOA	yııc	iiiics (itew)		
	Date : Tuesday, 21-4- 00 a.m. to 2.00 p.m.	2015			Total Marks :	70
Ins	tructions: 1) Q. (1)	and (2) are comp	uls	ory.		
	2) Answe	er any three ques	tion	s from Q. 3 to 0	Q. 7 .	
	3) All que	estions carry equ	al m	narks.		
1. Objec	etives.					14
•	noose correct alterna	tive :				8
•	Stationary charges p			field.		
,	a) Electrostatic	,		Magnetostatic		
	c) Both		-	None of these		
2)	Incident and transmi	tted waves are alv	,			
-)	a) In phase	tiod waves are are	-	Out of phase		
					n1	
	c) Out of path		a)	Depends on v	alue of ${n2}$	
3)	When wave gets rephase change of		urfa	ce of denser m	nedium there is a	
	a) 0°	b) 90°	c)	180°	d) 270°	
4)	Total outward flux or is equal to	•	on '	B' through any	close surface 'S'	
	a) One	b) Infinite	c)	Φ	d) Zero	
5)	The total power radio			of radius of	f sphere, which is	
	a) Dependent, ener	Эy	b)	Independent, e	energy	
	c) Dependent, mom	entum	d)	None of these		
					P.7	T.O.



6)	Steady current produce	fields that are
	in time.	

a) Magnetic, constant

b) Magnetic, variable

c) Electric, constant

- d) None of these
- 7) Potential function 2x² + 2y² + 2z satisfy_____
 - a) $\nabla^2 \phi = 0$

b) $\nabla^2 \phi \neq 0$

c) $\nabla^2 \phi = \rho / \epsilon_0$

- d) All of these
- 8) The total power radiated by an oscillating dipole is ______to the ______to the ______
 - a) Proportional, fourth
 - b) Inversely proportional, fourth
 - c) Inversely proportional, third
 - d) proportional, third

B) True / False:

6

- 1) In case of oblique incidence transmitted wave is always in phase with incident wave.
- 2) Magnetic vector potential due to magnetic dipole is proportional to r^{-3} .
- 3) Half wave antenna is a simply straight conductor.
- 4) Radiation resistance for half wave antenna is 73.2 ohms.
- 5) The speed which is significant proportion of the speed of light is called relativistic.
- 6) A plane wave scattered by an electron shows polarization and scattering.
- 2. Write the short notes (any three):

- 1) Wave equation in terms of electromagnetic potential.
- 2) Skin depth.
- 3) Terminology of sin wave
- 4) Polarization of EM wave.



3.	a)	Give the interaction between two current loops.	8
	b)	Give the expression for energy stored in electric and magnetic fields.	6
4.	a)	Explain reflection and refraction of electromagnetic wave across the interface for the case of oblique incidence.	8
	b)	Give electromagnetic wave equation for the wave travelling through free space.	6
5.	a)	Write the equations of linear quadrupole potential and field.	8
	b)	Write integral forms of Maxwell's equations.	6
6.	a)	Write in detail Lienard-Wiechert potential.	8
	b)	Explain radiation damping.	6
7.	a)	Explain radiation form an oscillating electric dipole.	8
	b)	Explain radiation form half wave antenna.	6



Seat	
No.	

M.Sc. (Part – I) (Semester – II) Examination, 2015

	•	aterials Science) (New) echniques (Paper – VIII)
Day and Date : Thurs Time : 11.00 a.m. to :	-	Total Marks : 70
Instructions	2) Answer any3) All question	2 are compulsory . three questions from Q. 3 to Q. 7 . Is carry equal marks. Able or nonprogrammable calculator is
1. Objective questi	ons:	14
a) Select correc	t alternative :	8
1) The mass	absorbance coeff	ficient of X-rays depend upon
a) Atomic	weight	b) Atomic number
c) Volume	e electron	d) Number of neutron
2) Bremsstra	nlung consist	wavelength of radiation.
a) single		b) two
c) triple		d) multiple
3) The Beer-l	_ambert law is the	e linear relationship between
a) Absorp	tion and wavelen	gth
b) Voltage	e and analyte con	ncentration
c) Absorp	tion and concent	tration of an absorbing species
d) Absorp	otivity coefficient a	and pathlength
4) XPS worki	ng is based on pr	rinciple of
a) Photoe	electric effect	b) Photovoltaic effect
c) Lambe	rts law	d) 200-800 nm

2.



	5)	Infrared spectroscopy provides valual	ble	information about	
		a) Molecular weight	b)	Melting point	
		c) Functional group	d)	Conjugation	
	6)	Which of the following spectroscopic penergy?	pro	cess requires the conservation of	
		a) Absorption	b)	Emission	
		c) Scattering	d)	All of the above	
	7)	Which of the following properties must active?	st c	hange for a mode to be Raman	
		a) Volume	b)	Dipole moment	
		c) Polarisability	d)	All of the above	
	8)	A compound showing IR absorption in the presence of		•	
		a) $C \equiv N$ b) $C \equiv C$	c)	C=C d) $C=O$	
b)	St	ate True or False :			6
	1)	An X-ray spectrum gives the relative photon.	e n	umber of X-rays emitted at each	
	2)	Ultra high vacuum is used in XPS to incions and photons.	rea	se the mean free path for electrons,	
	3)	The Raman shift depends on the ener	rgy	spacing of the molecule's mode.	
	4)	Minimum energy required to ionize hy 11.6 eV.	/dr	ogen atom from its ground state is	
	5)	IR spectroscopy is helpful for identific	ati	on of organic compound.	
	6)	Deuterium lamp is a source of visible	ra	diation.	
W	rite	short notes :			14
1)	Va	arious modes of vibrations in a molecu	ıle.		5
2)	De	epth profiling in XPS.			5
3)	St	ructure factor in crystallography.			4



3.	a)	How are the lattice parameters of tetragonal and hexagonal structures are determined? Explain with an appropriate diagram and derivations.	8
	b)	Describes the instrumentation and working of FTIR spectrometer.	6
4.	a)	Why Fourier Transform IR spectroscopy more useful than dispersive IR spectroscopy ?	10
	b)	What is chemical shift?	4
5.	a)	Explain the working and principle of a double beam UV-VIS spectrophotometer with block diagram?	8
	b)	State Bragg's law and explain the working of X-ray diffractometer.	6
6.	a)	What is Attenuated Total Reflection technique? How it can be used analyze the specimen?	8
	b)	What is the importance of Raman spectroscopy? What the stokes and anti-stokes line indicate in the Raman spectra?	6
7.	a)	Write a note on selection rules in simple harmonic oscillator in parallel and perpendicular vibration. Explain skeletal vibration and why it is different from characteristic group vibration.	8
	b)	What are different types of bonds present in materials? Discuss with an appropriate example.	6

8

Seat	
No.	

a) 1

b) 0

M.Sc. (Part – I) (Semester – II) Examination, 2015 PHYSICS (Materials Science) Paper – V : Statistical Mechanics (Old)

		- V : Statistical	•	ld)
-	ate : Thursday, 16- 00 a.m. to 2.00 p.m			Total Marks :
Inst	3) Atte	empt five questions I and Q. 2 are com empt any three fro ure to right indicat	n pulsory . m Q. 3 to Q. 7 .	
1. A) Cho	oose correct altern	ative :		
1)	Boltzmann's limit	of Bosons and Fer	rmions is	
	a) $e^{\beta\mu} \ll 1$	b) $e^{\beta\mu} >> 1$	c) $e^{+\beta\mu} >> 1$	d) $e^{-\beta\mu} >> 1$
2)	The total energy of a) $E = P^2/m$ c) $E = P^2/2 + 1/2$	-	h is a constant of b) $E = P/2m$ d) $P^2/2m + 1/2 F$	motion is given by Kq^2
3)	'μ' space for singa) Two dimensionc) Six dimension	nal	b) Three dimens	
4)	Louville's equation a) Pressure	n gives the rate of b) Temperature	=	d) Volume
5)	Temperature at cr a) 3b	•	c) 3b/27Rb	d) 8a/27Rb
6)	$\ensuremath{^{^{\circ}}}\alpha\ensuremath{^{^{\circ}}}$ is related with	chemical potentia	I (μ) by the relati	on
	a) kT/μ	b) $-\mu/kT$	c) μ/β	d) $\mu T/k$
7)	Gibbs potential is a) $G = E - PV + R$ c) $G = E - PV - R$	ΓS	on b) G = E + PV + d) G = E + PV -	
8)	At a critical point of	dp/dv =		

d) -1

c) ∞

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	B)	State true/false :	6
		 Clasius-Clapeyron equation gives rate of change of pressure along equilibrium curve. 	
		2) Diffusion process is irreversible.	
		 The point at which the vapour pressure curve abruptly terminates is called transition point. 	
		4) The equation of reduced state requires the values of constants a and b.	
		5) Gibbs paradox is related to entropy change.	
		6) In micro canonical ensemble both energy and mass is conserved.	
2.	At	tempt following :	14
	a)	Energy fluxuations in canonical ensemble	
	b)	Microstates and macrostates	
	c)	Law of corresponding states.	
3.	a)	What is Gibbs paradox ? How it is resolved ?	10
	b)	Explain phase transition using PT diagram.	4
4.	a)	Give the condition for ideal Bose gas.	10
	b)	Explain grand canonical ensemble.	4
5.	a)	By using Vander walls equation of reduced state, calculate the values of critical constants.	10
	b)	What is phase space and quantum state?	4
6.	a)	What is Brownian motion? Write Langivin's theory of Brownian motion.	8
	b)	Explain fluctuation dissipation theorem.	6
7.	a)	Show that average energy of single particle of ideal fermi gas is 3/5 times the Fermi energy of the system.	10
	b)	Write about MB statistics.	4



c) Cosmology

M.Sc. (Part – I) (Semester – II) Examination, 2015 PHYSICS (Old) Material Science

Paper No. - VI: Quantum Mechanics

ay and Date : Saturday, 18-4-2015 Total Marks :		: 70
Time: 11.00 a.m. to 2.00 p.m.		
Instructions: 1) Q.No. 1 and Q. I	No. 2 are compulsory .	
2) Attempt any thr	ee questions from Q. No. 3 to Q. No. 7.	
3) All questions ca	erry equal marks.	
1. A) Choose correct alternatives :		8
1) For a given $\psi(x)$, $\int \psi^* \psi . d^3 x = 0$ sanywhere is	says that probability of finding the object	
a) zero	b) constant	
c) the wavefunction is absent	d) the wavefunction vanishes	
2) Dirac delta is used with		
a) discrete observables	b) antisymmetrized observables	
c) continuous observables	d) bra and ket notations	
3) The points inside the box where	the wavefunction is zero are called	
a) Quantum numbers	b) Nodes	
c) energy levels	d) Solutions	
4) The exact solution of many-body	can be obtained in	
a) Classical mechanics	b) Quantum mechanics	

d) None of the above, nor elsewhere



	5)	Compared to the electron with a having lower angular momentum	_	er angular momentum, the electron	
		a) Away from the nucleus	b)	Nearer the nucleus	
		c) Has a thicker orbital	d)	None of the above	
	6)	The no. of electrons circulating at hydrogen like atom is	oou	t the positively charged nucleus in a	
		a) Equal to the number of proton	s in	nucleus	
		b) Equal to mass number			
		c) Negligible			
		d) One			
	7)	In atoms having many electrons,	the	electron repulsion term	
		a) can be ignored			
		b) can be included in the momen	tum	operator	
		c) has to be included in the poter	ntia	l energy term of wave equation	
		d) none of the above			
	8)	The Born-Oppenheimer approxim	nati	on is valid for	
		a) The ground electronic state of	the	e molecule	
		b) The excited electronic state of	f the	e molecule	
		c) Both the above			
		d) None of the above			
B)	Fill	l in gaps.			3
	1)	An observable can be represented	d by	,	
	2)	Any operator that commutes with a constant of motion.	the	operator is called	
	3)	Separation of electronic and nuc principle.	elea	r function describes the	



C) State **True** or **False**:

		1) ψ and its derivative with respect to its variables are continuous.	
		2) For a free particle the momentum operator is a constant of motion.	
		3) The wave function of a system must be symmetric with respect to interchange of every pair of electrons.	
2.	At	tempt any three :	14
	a)	Write a short note on QM wave function $\boldsymbol{\psi}$ and its interpretation.	
	b)	State and explain the second postulate of quantum mechanics.	
	c)	Write a note on many electron atoms.	
	d)	Write a note on Born-Oppenheimer approximation and justify it using experimental data for the Hydrogen molecule.	
3.	a)	What is the general procedure for setting up a quantum mechanical operator? Illustrate it by setting up operators for	10
		i) Components of linear momentum	
		ii) The Hamiltonian and	
		iii) Components of angular momentum.	
	b)	Find the energy jump in electron volts for the emission of visible light of wave-length 7500 Å.	4
4.	a)	Considering the de Broglie wave associated with a moving particle, derive Schrodinger equation. Generalize it to three dimensions. How would interpret the wave function ψ ?	10
	b)	Show that the product of two Hermitian operators is Hermitian if they commute.	4



5.	a)	Define and solve the energy eigenvalue problem for a harmonic oscillator.	
		What is zero point energy?	10
	b)	For the ground state of the one-dimensional harmonic oscillator show that the average value of its kinetic and potential energies are equal.	4
6.	a)	Formulate the Schrodinger equation for many electron atoms. Why these equations cannot be solved? What is the method suggested by Hartree?	10
	b)	Show that electron density in a filled shell of orbitals, like the configuration p^6 and d^{10} , is spherically symmetrical.	4
7.	a)	Stating the basic assumptions involved, develop the molecular orbital theory for an n-atom molecule.	10
	b)	Show that L+ and L- are not but L - L+ and L + L - are Hermitian.	_

Seat	
No.	

M.Sc. (Part – I) (Semester – II) Examination, 2015 PHYSICS (MATERIALS SCIENCE) (Old) Paper – VII: Physical Chemistry

Total Marks: 70 Day and Date: Tuesday, 21-4-2015

Time: 11.00 a.m. to 2.00 p.m.

Instructions: 1) Attempt **five** questions.

- 2) Q. 1 and Q. 2 are compulsory.
- 3) Attempt any three from Q. 3 to Q. 7.
- 4) Figures to **right** indicates **full** marks.
- 1. Select correct alternative:

14

- 1) Enthalpy of an exothermic reaction is _____
 - a) always zero

b) always negative

c) always positive

- d) may be positive or negative
- 2) Which of the following expression is correct for the first order reaction $(A_0$ refers to initial concentration).

- a) $t_{1/2}^{\alpha} \alpha A^1$ b) $t_{1/2}^{\alpha} \alpha A^{-1}$ c) $t_{1/2}^{\alpha} \alpha A_0$ d) $t_{1/2}^{\alpha} \alpha A^2$
- 3) Hess's law is applicable to _____
 - a) rate of reaction
 - b) equilibrium constant
 - c) changes in heat of reaction
 - d) the influence of pressure on reaction rate
- 4) Which of the following reaction is correct where, terms have their usual meaning?

a)
$$\Delta s = \frac{1}{T} (\Delta H - \Delta G)$$

b)
$$\Delta H = \Delta G - T \Delta S$$

c)
$$\Delta S = \frac{1}{T} (\Delta G - H)$$

d)
$$\Delta H = \Delta G + T\Delta S$$



5)	The concentration of the reactants is reduced to 25% for a first order reaction
	in one hour. The half life period of the reaction is

- a) $\frac{1}{2}$ hr b) $\frac{1}{4}$ hr c) $\frac{3}{4}$ hr
- d) 4 hr
- 6) Which of the following reaction is correct?
 - a) $\left(\frac{\partial S}{\partial P}\right)_{T} = \left(\frac{\partial V}{\partial T}\right)_{B}$
- b) $\left(\frac{\partial V}{\partial T}\right)_{P} = \left(\frac{\partial S}{\partial V}\right)_{T}$

c) $\left(\frac{\partial G}{\partial T}\right)_{B} = S$

- d) $\left(\frac{\partial S}{\partial V}\right)_T = \left(\frac{\partial P}{\partial T}\right)_V$
- 7) Which of the following will form a cell with the highest voltage?
 - a) $1M A_{\alpha}^{+}$, $1M CO^{2+}$
- b) $2M A_{q}^{+}, 2M CO^{2+}$
- c) $0.1M A_0^+$, $2M CO^{+2}$
- d) $2M A_a^+$, $0.1M CO^{+2}$
- 8) The e.m.f. of a galvanic cell composed of two hydrogen electrodes is 272 mV. What is the pH of the solution in which the anode is immersed if the cathode is in contact with a solution of pH = 3.
 - a) 3

b) 6.7

c) 7.6

- d) 10
- 9) The electrode potential of hydrogen electrode in neutral solution at 298 K is _
 - a) -0.41 V

b) zero V

c) -0.49 V

- d) 0.41 V
- 10) What is CMC of solution?
 - a) calculated Molar concentration
 - b) critical Micelle concentration
 - c) coulombic mass charge
 - d) curies magnetic constant
- 11) Which of the following has no effect on the rate of a reaction?
 - a) enthalpy change
- b) temperature

c) catalyst

d) concentration of reactants



2.

			3	•
12)	The Arrhenius equation of effect o reaction is	f tei	mperature on the rate constant of a	
	a) $K = A.e^{-\epsilon a/RT}$	b)	$K = \log \left(\frac{\varepsilon a}{RT} \right)$ $K = \frac{\varepsilon a}{RT}$	
	c) $K = e^{\frac{-\epsilon a}{R^2T}}$	d)	$K = \frac{\varepsilon a}{RT}$	
13)	According to the third law of therm	ody	ynamics at 0°K the entropy is zero for	
	 a) Covalent solids at 25 atm press b) Elements in their stable form c) Perfectly crystalline solids d) Any compound in their liquid form 		e	
14)	Which of the following is anionic sa) CTABb) Sodium dodecyl sulphatec) Benzyl thionium chlorided) Cetrimonium chloride	urfa	actant ?	
Atte	empt the following :			14
a)	What is partial molar entropy and	hov	vit can be determined by calorimetry?	5
b)	Derive the relationship between the fast reaction	ne re	elaxation time τ and K_1 and K_2 for	
	$A + B \stackrel{K_2}{\rightleftharpoons} C$			5
c)	What is EMF? Give applications of	of E	MF.	4

) Evalois the terms estivity coefficient and mean ionic

3. a) Explain the terms activity coefficient and mean ionic activity coefficient. Discuss in detail the Debye-Huckel theory of mean ionic activity coefficient.

10

b) Explain electrodeposition technique for any of electrochemically active compound of your choice.

4

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4

4. a) Define the terms Gibbs free energy and Helmholtz free energy. How is each of these terms related to maximum work that can be done by a system during a given change? Discuss the variation of ΔG with variation in i) Temperature and pressure. 10 ii) Pressure and volume. b) Explain the terms fugacity and activity. How are they related to chemical potential? What is the physical significance of fugacity? 4 5. a) Explain the RRKM Theory of unimolecular reaction rate. 10 b) Discuss dynamics of parallel and complex reactions. 4 6. a) Discuss the collision state theory for bimolecular reaction rates. Compare between transition and collision state theories. 10 b) What is decomposition potential? How it can be determined experimentally? 4 7. a) What are concentration cells? Derive expressions for the emfs of concentration cells 10 i) With transference ii) Without transference.

b) Derive, $C_P - C_V = R$. Define the terms involved in the equation.



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M.Sc. (Part – I) (Semester – II) Examination, 2015 PHYSICS (Materials Science) (Old) Paper - VIII: Analytical Techniques - II

Day and Date: Thursday, 23-4-2015 Total Marks: 70

Time: 11.00 a.m. to 2.00 p.m.

Instructions: 1) Q. No. (1) and (2) are compulsory.

- 2) Attempt any three from Q. No. 3 to Q. No. 7.
- 3) All questions carry equal marks.
- 1. A) Choose the correct alternatives:

8

- 1) Which of the following statement is most correct about Atomic Force Microscopy (AFM)?
 - a) AFM can visualize protein bound to DNA molecules
 - b) AFM can visualize unfixed specimens in water or buffer
 - c) AFM moves a very sharp tip over the surface of the specimen to "feel" its shape
 - d) All the statements above are true
- 2) A photon with energy of one electron volt (1 eV = 1.602×10^{-12} ergs) has a wavelength of
 - a) 1.24×10^{-2} cm
- b) 3720 Å
- c) 3.0×10^{-5} cm
- d) 1,240 Å
- 3) The energy of photon absorbed by an atom will be equal to
 - a) Ionization energy + Kinetic energy
 - b) Ionization energy
 - c) Kinetic energy
 - d) Ionization energy Kinetic energy
- 4) Which type of scattering results in stronger wavelength than the incident light?
 - a) Rayleigh
- b) Stokes
- c) Anti-stoke d) None of the above

B)



5)	A microscope in which an image in formed by passing an electron beam through a specimen and focusing the scatters electron with magnetic lenses is called a		
	a) Scanning tunneling microscope		
	b) Scanning electron microscope		
	c) Atomic force microscopy		
	d) Transmission tunneling microscope		
6)	IR spectroscopy is helpful for		
-,	a) Identification of organic compound		
	b) Following progress of a reaction		
	c) Both (a) and (b)		
	d) None of the above		
7)	The structure factor is particularly useful tool in the interpretation of interference pattern in		
	a) X-Rays b) Electrons and neutrons		
	c) Diffraction experiment d) All of the above		
8)	The wavelength of continuous X-rays depends upon a) Target materials b) Filament current c) Accelerating potential difference d) All of the above		
Fil	l in gaps :	6	
i)	Atomic force microscopy can be operated different modes.		
ii)	The coordination number of hcp structure is		
iii)	are used to produce photoelectrons in XPS.		
iv)	The ultraviolet photoelectron spectroscopy was developed to study the photoelectron spectra of free molecules in the phases.		
v)	The finger print region in the IR spectrum is to cm ⁻¹ .		
vi)	Elastic scattering of photon is known as scattering.		



2.	Wr	rite a notes on :	6
	1)	Advantages of AFM over the conventional microscopy techniques.	5
	2)	Explain the interaction electron with matter.	5
	3)	Explain the terms :	
		i) Acquisition of raw data and	
		ii) Data processing in X-ray diffraction techniques.	4
3.	a)	Draw schematic diagram of the scanning electron microscopy and explain the experimental details along with image formation and detectors used.	8
	b)	Explain the working principles of IR spectroscopy.	6
4.	a)	Describe the instrumentation and working of X-ray diffractometer.	8
	b)	Explain valence band analysis and work function measurement in UPS.	6
5.	a)	Explain the theory of Infrared absorption in IR spectroscopy. With the help of a typical FTIR spectrometer layout explain how the constructive and	8
	ل ما	destructive interference pattern generated.	
	D)	Write a note on ultraviolet photoeletron spectroscopy.	6
6.	a)	Explain the principle and working of Raman spectroscopy.	8
	b)	What is the Bragg diffraction condition, assume the X-rays fall on the crystal	
		planes at some grazing angle θ ? How the crystalline size is estimated from the incidence of X-ray's on the crystals ?	6
7.	a)	Explain the working and principle of X-rays photoelectron spectroscopy with appropriate block diagram.	8
	b)	Explain the difference between WDS and EDS.	6

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М.	PHÝSICS (M	r – III) Examination, 20 aterials Science) niconductor Devices)15
Day and Date: Wedr Time: 3.00 p.m. to 6	•		Max. Marks
Instructions	3) Attempt any 3 fr	ions. d 2 are compulsory . rom questions 3 to 7. rammable calculator is all o	owed.
1. Choose the corr	ect alternative :		
1) The safety fa	actor for a power diod	e is given by	
a) $\frac{t_a}{t_b}$		b) $t_b t_a$	
c) $\frac{1}{t_a \cdot t_b}$		d) $t_a \cdot t_b$	
2) A transistor i	is said to have a force	ed β (β_F) when β is	
a) $\frac{I_C(sat)}{I_B}$		b) $\frac{I_B}{I_C(sat)}$	
c) l _B ⋅l _C (sat)	d) $\frac{1}{I_B \cdot I_C(sat)}$	
3) Which of the	following is better the	an CMOS inverter?	
a) DTL		b) RTL	
c) TTL		d) ECL	
4) MOS control	lled thyristor is a comb	oination of	_

c) Thyristor and a thyristor d) Thyristor and a MOSFET

a) Thyristor and a transistor

b) Thyristor and a diode

5)	A triac is a combined effect of two SCR's	s connected in
	a) Series	b) Parallel
	c) Antiparallel	d) Both a) and b)
6)	For an ideal MIS diode E_F remains con	stant in the semiconductor because
		
	a) $\frac{dI}{dx} = 0$	b) $\frac{dI}{dx} \neq 0$
	c) Both a) and b)	d) None
7)	The ground state degeneracy of an acce	epter is
	a) 1	b) 2
	c) 3	d) 4
8)	In an ideal MOS diode, the surface semiconductor is	e potential (ψ_s) deep inside the
	a) $\psi_s = \psi_{max}$	b) $\psi_s = \psi_{min}$
	c) $\psi_s = \frac{\psi_{max}}{z}$	d) $\psi_s = 0$
9)	An intrinsic Debye length for holes is	
	a) $\sqrt{\frac{KT \in S}{p_{p_0}}}$	b) $\sqrt{\frac{K.T. \in_s}{n_{p_o} \cdot q^2}}$
	c) $\sqrt{\frac{K. \in S}{p_0 \cdot q}}$	d) $\sqrt{\frac{K. \in_s}{n_p \cdot q}}$
10)	Flat band shift is due to	charges.
	a) Mobile ionic	b) Fixed oxide
	c) Oxide trapped	d) Interface trapped
11)	Light emission is not possible in Si beca	use of its
	a) direct band gap	b) high mobility
	c) indirect band gap	d) carrier concentration
12)	D-MOSFET means MO	SFET.
	a) Double dimensional	b) Depleted
	c) Double diffused	d) Dimensionless



	13)	Resonant tunneling diode has a cut-of range.	f fı	requency in the	
		a) KHz	b)	MHz	
		c) GHz	d)	THz	
	14)	The dominating operating process in PV-c	dete	ector/Solar cell is	
		a) Stimulated emission	b)	Absorption	
		c) Reflection	d)	Transmission	
2.	Att	empt any three.			14
	1)	Explain reverse recovery characteristic	of a	a power diode.	5
	2)	Write a note on triac.			4
	3)	What is a CMOS?			5
	4)	Conductance measurement technique for	or n	neasurement of surface traps.	4
3.	a)	What is a MCT? With a block construction turn OFF process in MCT's?	ona		10
	b)	State the important applications of MCT	•		4
4.	a)	Explain the variation of total capacitance voltage.	of a	•	10
	b)	What is flat bad condition? State the ma Interpret it.	ıgn	itude of flat band capacitance.	4
5.	a)	Give a brief account of two transistor ar	alc	gy of a thyristor.	8
	b)	Write a note on interface trapped charge	es.		6
6.	a)	What is CCD? With a good sketch of an do you mean by accumulation, depletion and n-type semiconductors.		d inversion of the charges for the p	10
	b)	Compare the salient features of the above	ve p	processes.	4
7.	Att	empt the following:			14
	a)	Modern MOSFET's are fabricated on a	(10	00> oriented silicon – Comment.	6
	b)	Protection of a thyristor against $\frac{dv}{dt}$.			4
	c)	Transferred electron effect in GaAS.			4



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M.Sc. - II (Semester - III) Examination, 2015 PHYSICS (Materials science) Paper - X Instrumentation

Total Marks: 70 Day and Date: Friday, 17-4-2015 Time: 3.00 p.m. to 6.00 p.m. Instructions: 1) Q. (1) and (2) are compulsory. 2) Answer any three questions from Q.3 to Q.7. 3) All questions carry equal marks. 14 1. Objective questions. a) Choose correct alternatives. i) In LVDT, which of the following varies with the input displacement. a) resistance b) capacitance c) inductance d) temperature ii) A pH meter is used measure a) acidity of a solution b) alkalinity of a solution c) neutrality of a solution d) all of the above iii) In signal conditioning systems, an external excitation is required for a) Thermo couples b) Piezo-electric crystals c) Strain gauges d) Inductive pick-ups iv) In an op-amp logarithmic amplifier, the output voltage forms a logarithmic function of the a) input voltage b) output voltage c) reference voltage d) peak voltage

8



	v)	In lock-in amplifier, a phase se	ensitive detector circuit is basically a	
		a) Mixer	b) Comparator	
		c) Amplifier	d) Rectifier	
	vi)	Operations such as multiplicat	ion, division, power etc. can be done using	
		a) lock-in amplifier	b) DC amplifier	
		c) logarithmic amplifier	d) AC amplifier	
	vii)	Which of the following is a – ve	e temperature coefficient device	
		a) Thermocouple	b) Thermistor	
		c) Strain gauge	d) Loud Speaker	
	viii)	Supply of high voltage signals	can be prevented by using	
		a) Instrumentation amplifier		
		b) Active filters		
		c) Operational amplifier		
		d) Isolation amplifier		
	b) Fil	l in the blanks.		6
	i)	The output of the thermocouple	e is in the form of	
	ii)	Photo emissive cell is an	transducer.	
	iii)	Hydrogen ion concentration of meter.	a solution can be measured with	
	iv)	UPS requires for its o	peration.	
	v)	Revolutions per minute can be	measured using meter.	
	vi)	In SMPS, transistors are mainl	y used as devices.	
2.	Attem	pt any three.		14
	a) Dis	scuss the applications of tempe	rature sensors.	
	b) Wı	rite the feedback fundamentals.		
	c) Ex	plain the operation of RMS con	verter.	
	d) Wı	rite a note on dynamic signal filt	ering.	



3.	a)	Discuss the construction and operation of different types of temperature transducers.	10
	b)	Write the advantages and disadvantages of each of them.	4
4.	a)	Describe with neat diagram, the working of an isolation amplifier and explain with illustration how it is used to protect the system.	10
	b)	Write the applications of instrumentation amplifier.	4
5.	a)	Describe the construction and working of a digital storage oscilloscope.	10
	b)	Write a note on power meter.	4
6.	a)	With neat block diagram, explain the constructional features of a spectrum analyzer.	10
	b)	Discuss the static signal conditions.	4
7.	,	Explain the various functional blocks of a multichannel data acquisition system. Write the applications of logic state analyzer.	10 4



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M.Sc. II (Semester – III) Examination, 2015 PHYSICS (Materials Science) Paper – XI: Elements of Materials Science

Day and Date: Monday, 2 Time: 3.00 p.m. to 6.00 p				Total Marks : 70
2,) Q. (1) and (2) are con) Attempt any three fro) Figures to the right in	om (Q. 3 to Q. 7 .	
1. A) Choose the correct	ct alternative :			8
1) Strength of var	n der Waals bonds is		that of ionic	bonds.
a) less than		b)	greater than	
c) equal to		d)	none of the above	
Amorphous madisorder.	aterials have	_ ra	nge order and	range
a) long, long		b)	short, short	
c) short, long		d)	long, short	
3) Type of bondir	ng in Al is			
a) covalent		b)	metallic	
c) hydrogen		d)	van der Walls	
4) The solids that	t can absorb visible ligh	t ar	e	
a) semicondu	ctors	b)	metals	
c) insulators		d)	ceramics	
5) Electrical cond	luctivity of metals		_ with temperature.	
a) increases		b)	decreases	
c) do not chan	nge	d)	none of the above	



	6)	The process occurring in LED is		
		a) phosphorescence	b) radiation	
		c) electroluminescence	d) fluorescence	
	7)	Photodiodes are normally biased in	mode.	
		a) forward	b) reverse	
		c) both forward and reverse	d) none of the above	
	8)	One dimensional nanostructures are		
		a) Quantum dots	b) Quantum wells	
		c) Quantum wire	d) None of the above	
	B) Fi	ll in the gaps :		6
	1)	Relation between resistance and resis	stivity is	
	2)	Relation between electrical conductivi	ty and carrier mobilities is	
	3)	For intrinsic semiconductors the position	on of Fermi-energy level is	
	4)	Silicon carbide istype of m	aterial.	
	5)	At absolute zero, intrinsic semiconduc	ctor behaves like a	
	6)	Thermal conductivity of metals is very		
2.	Atten	npt any two :		14
	1) H	ow ceramics differ from polymers?		
	2) Ex	xplain the mechanism of polymerization	n.	
	3) Di	scuss one method to manufacture poly	mers.	
3.	a) Di	scuss the classification of engineering	materials.	6
	b) Di	scuss with example ionic bond and hyc	Irogen bonds.	8
4.	a) Di	scuss with a neat diagram crystal stru	cture of silicon.	6
	b) Di	scuss the effect of doping on carrier co	ncentration and mobilities.	8

5.	a)	Discuss the change in light intensity as light travels through a absorbing material.	6
	b)	What are different types of luminescence?	8
6.	a)	Explain the mechanism of photoconductivity in semiconductors.	8
	b)	Write short note on cathodoluminescence.	6
7.	a)	Explain the physics behind functioning of photodetectors.	8
	b)	Explain any one method that can be used for synthesis of nano structured materials.	6



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M.Sc. (Part - II) (Semester - III) Examination, 2015

		-	aterials Sciend and Ferroelec	-	
-	Date : Wednesday 0 p.m. to 6.00 p.			Total Marks :	70
Ins	•	nswer any thr e	ompulsory. ee questions from rry equal marks.		
1. Objec	ctive questions.				14
A) C	hoose the correc	t alternative :			6
1)	An electromagr $(kx - \omega t)$ and E			n is describe by $E = E_0 \sin \theta$	
	a) $E_0 k = B_0 \omega$		b) $E_0 B_0 = \omega k$		
	c) $E_0 \omega = B_0 K$		d) None of thes	е	
2)	The differential	form of Gauss'	s law in CGS sys	tem is	
	a) $\nabla . \overline{E} = \rho / \varepsilon_0$		$b)\in {}_{o}div^{\cdot}\bar{E}:$		
	c) $\nabla . \overline{E} = 4\pi \rho$		d) $div \overline{E} = 4\pi\sigma$		
3)	Polarization in	a dielectric on a –	application of ele	ctric field is	
	a) Displacemen	t/separation of	opposite charge	centres	
	b) Passing of cu	ırrent through d	ielectric		
	c) Breaking of ir	nsulation			
	d) Excitation of	electrons to hig	her energy level	3	
4)	Above curie tem material is	nperature, the s	pontaneous pola	rization for ferroelectric	
	a) zero	b) 1	c) $\frac{1}{2}$	d) infinity	

8) The piezo-electric property of a crystal is the principle of quartz clock.

3. a) Discuss in detail electric polarization of dielectric material and its relaxation in

b) Give the difference between luminescence and fluorescence.

14

5

5

4

10

4

6) Solar cell works based on photo-conduction.

7) Fluorescence occurs within 10^{-5} ms.

2. Write short answers:

1) State and prove Gauss law.

static electric field.

2) Establish Clausius-Mosotti equation.

3) Explain in brief photovoltaic effect.

- 4. a) Sketch the equilibrium phase diagram of the Pb(Zr, Ti)O₃ system and explain microstructure of the unit cell for different phases.
 10
 - b) What are PTC materials?
- 5. a) Discuss in detail phenomenological properties and mechanism for BaTiO₃ crystal.10
 - b) Enlist the any four applications of piezoelectrics.
- 6. a) Discuss the space charge polarization and hopping polarization in case of any class of ferroelectrics.
 - b) State the Kramers-Kroning equation.
- 7. a) Prove that the following Maxwell's equations $\nabla \times \overline{E} = -\frac{\partial \overline{B}}{\partial t}$ and

$$\nabla \times \overline{H} = \overline{J} + \frac{\partial \overline{D}}{\partial t}.$$

- b) Define:
 - i) Unit of Debye.
 - ii) Chemical unit of mole.



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M.Sc. (Part – II) (Semester – IV) Examination, 2015 PHYSICS (Material Science)

Paper - XIII: Computational Methods and Programming

Day and Date: Thursday, 16-4-2015 Max. Marks: 70

Time: 3.00 p.m. to 6.00 p.m.

Instructions: 1) Q. No. 1 and Q. No. 2 are compulsory.

- 2) Answer any three questions from Q. No. 3 to Q. No. 7.
- 3) **Use** of non programmable calculator is **allowed**.
- 4) All questions carry equal marks.
- 1. a) Choose the correct alternative.

6

- i) The order of convergence in Newton Raphson method is
 - A) 2

B) 3

C) 0

- D) 1
- ii) If $y = ae^{cx}$, then the first normal equation is $\sum log y =$
 - A) an + $\log c \sum x$
 - B) $a \sum x + c \sum x^2$
 - C) n log a + c $\sum x$
 - D) a $\sum x + c \sum x^3$
- iii) The Newtons forward difference formula is most suitable for the case where independent variable is present at
 - A) lower part
 - B) upper part
 - C) central part
 - D) any where in the difference table



iv) Gauss for n = 2 for the $\int_{-1}^{1} f(x) dx$ is

A)
$$f\left(-\sqrt{\frac{5}{3}}\right) + f\left(\sqrt{\frac{5}{3}}\right)$$

B)
$$f\left(-\sqrt{\frac{3}{5}}\right) + f\left(\sqrt{\frac{3}{5}}\right)$$

C)
$$f\left(-\sqrt{\frac{2}{3}}\right) + f\left(\sqrt{\frac{2}{3}}\right)$$

D)
$$f\left(-\sqrt{\frac{1}{3}}\right) + f\left(\sqrt{\frac{1}{3}}\right)$$

- v) Using Runge Kutta method of order four, the value of y(0.1) for y' = x 2y, y(0) = 1, taking h = 0.1, is _____
 - A) 0.813
- B) 0.825
- C) 0.0825
- D) 0.0813
- vi) Adams Bashforth method is used for
 - A) Solving integral equations
 - B) Solving differential equation
 - C) Evaluating integrals
 - D) Differentiation
- b) State **true** or **false** or fill in the blanks.
 - i) To fit the equation $y = a + bx + cx^2$ by least square principal, the number of normal equations will be 3.
 - ii) The Lagrange's interpolation formula is used for both equally spaced as well as unequally spaced data.
 - iii) Using intermediate value theorem, the root of the equation f(x) = 0 lies between [a, b] provided f(a). f(b) < 0.
 - iv) The interval in which the a real root of equation $x^3 2x 5 = 0$ lies is
 - v) Gauss-Jordan matrix inversion method is valid for only if the coefficient matrix "A" is singular.





- vi) To fit a straight line y = a + bx the second normal equation using the method of least square will be $\sum xy = a\sum x + b\sum x^2$.
- vii) In Predictor-corrector methods four initial values may be found with the help of Runge-Kutta method.
- viii) The Newton Raphson method fails when _____ is zero.
- 2. Write short notes on:
 - a) Write a note on Randam Walks.

b) Write note on normal equations for the curve $y = ax^b$.

4

c) Explain Bisection method and derive its nth iteration formula.

5

3. a) The following data are taken from the steam table:

6

Temperature T in °C	140	150	160	170	180
Pressure kgf/cm ²	3.685	4.854	6.302	8.076	10.225

Find the pressure at temperature $t = 175^{\circ}$ C.

b) Explain the principal of least square for the fitting a curve from given data. Fit a curve $y = ax^2 + bx + c$ to the following data.

8

x :	1	2	3	4	5
y :	5	12	26	60	97

4. a) Solve for a positive root of $xe^x - 3 = 0$ by regula False method, correct to three decimal places. Also solve $x^3 - 2x - 1 = 0$ by bisection method.

10

b) Solve the following system of equations by Gauss elimination method

4

$$x + 2y + z = 3$$

$$2x + 3y + 3z = 10$$

$$3x - y + 2z = 13$$



- 5. a) Given $\frac{dy}{dx} = xy + y^2$ with y(0) = 1 find y at x = 0.1, 0.2, 0.3 by Runge Kutta method of fourth order. Also find the y at x = 0.4 using Milne's method.
- 8
- b) Solve the following system of equation by Gauss Seidal method

$$8x - y + z = 18$$
.

$$2x + 5y - 2z = 3$$

$$x + y - 3z = -16$$

6. a) Use Gauss Jordan matrix inversion method to solve

8

$$x + y + z = 8$$

$$x - y + 2z = 6$$

$$3x + 5y - 7z = 14$$

b) Solve $\frac{dy}{dx} = x^2y - 1$ with y(0) = 1 find y at x = 0.1 and at x = 0.2 by Taylor's series method.

6

7. a) Evaluate $\int_{0}^{1} \frac{1}{1+x} dx$ by two and three point Gaussian quadrature formula.

6

b) Evaluate $\int_{0.2}^{1.4} (\sin x - \log x + e^x) dx$ using Simpson's one third and Simpsons three eighth rule.

8



Seat	
No.	

		PHYSICS (Mater	rial Science) (Pa	•	
Day ar	nd Date : Sat	turday, 18-4-2015		Total Marks	: 70
Time :	3.00 p.m. to	6.00 p.m.			
In	structions :	4) Figures to the		arks.	
1. CI	noose the co	orrect alternative :			14
i)	The interst	itial voids in silicon	for receiving an imp	urity atom are	
	a) 8	b) 4	c) 5	d) 7	
ii)	The impuri	ty profile in an inter	stitial diffusion is		
	a) logarithi	mic b) erf.C	c) linear	d) gaussian	
iii)		lectronic application direction.	s, growth of single c	rystal silicon must be along	
	a) (111)	b) (101	c) (011)	d) (110)	
iv)	An aspect	ratio is			
	a) L _W	b) R/L	c) W/L	d) L/R	
v)	Α	_ photoresist is pop	ularly used for IC-fa	brication.	
	•	Kodak – 820	b) Novolac		
	c) KPR		d) Isopoly-K-7	17 MR	
vi)	The purple	· -	_		
	a) AuAl ₂	b) AuAl	$_3$ c) Al_2O_3	d) AuAl	
vii)	_		of an epilayer and t	ne substrate are	
	•	each other	b) the same		
	c) different	t	d) none of the at	oove	



viii)	The base width of a n	ormal npn	transistor is of the orde	er of	μm .		
			b) 6 to 8 μm				
	c) 0.6 to 0.8 µm		d) 0.06 to 1 μm				
ix)	In constant source diff of impurity.	fusion, diffu	usion source consists o	f	amount		
	a) a finite		b) zero				
	c) an infinite		d) finite as well as infinite				
x)	1 mil = inc	ch.					
	a) 10^{-3}	b) 10 ⁺³	c) 10 ⁴	d) 10 ⁻⁴			
xi)	A dielectric isolation _		the parasitic capaci	itance.			
	a) reduces		b) does not affect				
	c) increases	c) increases d) none of the above					
xii)	An important advantage temperature process.		plantation is that the pro	ocess is a			
	a) low	b) high	c) intermediate	e d) excess	ively high		
xiii)	Minimum aspect ratio	is					
	a) 1:1	b) 1:5	c) 1:10	d) 1:3			
xiv)	In metallization, conta	acts are us	ually made with				
	a) Au	b) Mg	c) P	d) AS			
2. At	tempt any three:				14		
a)	Photographic mask						
	b) Czechrlaski technique						
c)	c) Boron gettering						
d)	Discuss : epitaxy Vs. diffusion.						
3. a)	Evaluate an epitaxial	layer throu	igh:				
	i) Measurement of s	heet resist	ance.				
	ii) Impurity profile.				10		
b)	Write a note on substi	itutional dif	fusion.		4		



4.	a)	State and explain Fick's second law of diffusion.	10
	b)	What is projected range?	4
5.	a)	Explain how an npn transistor is integrated using planar process.	10
	b)	Write a note on positive photoresist.	4
6.	a)	Give a brief account of ion implantation process.	10
	b)	What is complete oxide isolation?	4
7.	Wı	rite a note on :	14
	a)	Phosphorus diffusion system.	
	b)	Etch back effect.	
	c)	Wedge bonding.	

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Seat	
No.	

M.Sc. (Part – II) (Semester – IV) Examination, 2015 PHYSICS (Materials Science)

Paper – XI: Magnetic Materials

Day and Date: Tuesday, 21-4-2015 Total Marks: 70

Time: 3.00 p.m. to 6.00 p.m.

Instructions: 1) Q. (1) and (2) are compulsory.

- 2) Answer any three questions from Q. 3 to Q. 7.
- 3) All questions carry equal marks.
- 1. Objective questions.

14

a) Choose correct alternatives.

8

- 1) The coercivity of the material is a micro-structure sensitive property. This dependence is known as
 - a) Magnetic moment
- b) Magnetic shape anisotropy

c) Magnetization

- d) Susceptibility
- 2) Example for dia-magnetic materials
 - a) super conductors
- b) alkali metals
- c) transition metals
- d) ferrites
- 3) Example for anti-ferro-magnetic materials
 - a) salts of transition elements
- b) rare earth elements
- c) transition metals
- d) ferrites
- 4) The magnetic domains in a non-magnetized piece of iron are characterized by which orientation?
 - a) parallel to the magnetic axis
 - b) anti-parallel (opposite direction) to the magnetic axis
 - c) random
 - d) perpendicular to the magnetic axis

5) The inverse magnetostrictive effect is also known as



			a) Curie effect		b)	Neel effect		
			c) Weiss effect		d)	Villari effect		
		6)	A narrow transition	on region at the b	ou	ndary between	magnetic domains is	
			a) Bloch wall	b) Neel wall	c)	Curie wall	d) Weiss wall	
		7)	The property of for shape or dimens	_			them to change their ization is called	
			a) Magnetoresisc) Magnetostrict		,	Electrostrictio None of these		
		8)	The primary sou	rce of magnetoc	ryst	alline anisotro _l	py is	
			a) Spin motion		b)	Orbital motion		
			c) Spin-orbit inte	eraction	d)	None of these		
	b) \$	Sta	te true or false :					6
		1)	The magnetic douby perpendicular		_	-	iron are characterized	
		2)	Susceptibility of	antiferromagneti	ic m	aterials is large	e and negative.	
		3)	The area within volume of mater	_	-	represents the	energy loss per unit	
		4)	The phenomeno or ions occurs in	•		, ,	ween adjacent atoms sm.	
		5)	The paramagne vanishing angula	•	oos	sesses perma	nent dipoles due to	
		6)	A Néel wall is a r	narrow transition	reg	ion between m	agnetic domains.	
2.	Writ	e s	hort answers.					14
	a)	Wr	rite short note on	magnetic mome	nts	of atoms.		4
	b)	Ex	plain in brief mag	netostatic energ	y.			5
	c)	Dis	stinguish betweer	n ferromagnetic a	and	antiferromagne	etic orders.	5



3.	a)	Show that the susceptibility of diamagnetic substance is temperature independent.	10
	b)	Expalin the domains and domain walls.	4
4.	a)	Explain phenomenon of antiferromagnetism and show the inverse variation susceptibility with temperature.	8
	b)	Expalin the gyromagnetic ratio.	6
5.	a)	Discuss the Weiss theory of ferromagnetism.	8
	b)	Define Larmor precession. Explain it for magnetic dipoles.	6
6.	a)	Explain the origin of crystal anisotropy.	8
	b)	Write short note on magnetic resonance.	6
7.	a)	Explain Heigenberg model of molecular field theory.	8
	b)	Expalin in brief anisotropy in hexagonal crystals.	6



Seat	
No.	

M.Sc. – II (Semester – IV) Examination, 2015
PHYSICS (Materials Science)
Paper – XVI: Nano Science and Technology

Day and Date: Thursday, 23-4-2015 Total Marks: 70

Time: 3.00 p.m. to 6.00 p.m.

Instructions: 1) Attempt **five** questions.

- 2) Q. (1) and (2) are compulsory.
- 3) Attempt any three from Q. 3 to Q. 7.
- 4) Figures to the **right** indicate **full** marks.
- 5) **Use** of non programmable calculator is **allowed**.
- 1. Select the correct alternatives.

14

- 1) The hardest material in nature is,
 - a) Steel
- b) Topaz
- c) Diamond
- d) Quartz
- 2) The probe of scanning tunneling microscopy is as sharp as
 - a) An atom at the tip
- b) Many atoms at the tip

c) A needle

- d) None of the above
- 3) What is a bucky ball?
 - a) A carbon molecule (C_{60})
 - b) Nickname for Mercedes-Benz car
 - c) Plastic explosives nanoparticles
 - d) Concrete nanoparticles with high compressive strength
- 4) Which one of these statements is true?
 - a) Gold at the nanoscale is red
 - b) Copper at the nanoscale is green
 - c) Silicon at the nanoscale is insulator
 - d) Gold at the nanoscale is yellow



5)	vvnat is grapnene?						
	a) A new materials made from carbon nanotubes						
	b) A one-atom thick sheet of carbon						
	c) Thin film made of fullerenes						
	d) A software tool to measure and	d gr	aphically repr	esent nanoparticles			
6)	1 nanometer = cm.						
	a) 10^{-9} b) 10^{-8}	c)	10 ⁻⁷	d) 10^{-6}			
7)	Fermi level for p-type semiconduc	ctor	lies				
	a) At middle of the band gap	b)	Close to the o	conduction band			
	c) Close to the valence band	d)	None of the a	bove			
8)	Poole-Frenkel effect is present in						
	a) Metal	b)	Insulator				
	c) Conductor	d)	All of the abo	ve			
9)	X-rays which give a line spectrum are called as						
	a) Continuous X-rays	b)	Characteristi	c X-rays			
	c) K X-rays	d)	Bremstrallun	g X-rays			
10)	CBD is relativelyted	chn	ique compare	d to EBE.			
	a) Costlier		Cheaper				
	c) Both a) and b)	d)	None of the a	bove			
11)	The wavelength corresponding to the energy 3.02 eV is						
	a) 4100 A° b) 410 A°	c)	41 A°	d) 4.1 A°			
12)	The main technique used to calcu	late	e the band gar	o of a material is			
	a) FTIR spectroscopy	b)	UV-Vis absor	ption spectroscopy			
	c) NMR spectroscopy	d)	AAS spectros	scopy			
13)	Scanning electrum microscope is	be	st used to stud	dy			
	a) Small internal structure		Surface morp	hology			
	c) Band-gap	d)	Crystal struc	ture			
14)	In an electrolytic cell the electrode						
	is called the and the ch	em	iical change th	at occurs at this electrode			
	a) Anode, oxidation	þ)	Anode, reduc	tion			
	c) Cathode, oxidation	,	Cathode, red				
	o, Janiouo, omadiion	α)	Janiouc, icu	GOLIOIT			



2.	Att	tempt the following :	14
	a)	Explain Top-down and bottom-up approaches in nanotechnology.	
	b)	Explain the thermally activated conduction variable range hopping conduction and polaron conduction.	
	c)	Write note on Chemical Vapour Deposition.	
3.	a)	Explain lithographic process with its limitations. Give details of nanolithographic process.	10
	b)	Explain tapping mode in AFM and give its advantages.	4
4.	a)	What is elastic and inelastic scattering? Explain diagrammatically the signal generated by the interaction between electron beam and specimen.	8
	b)	Write a note on Schottky effect and Poole-Frankel effect.	6
5.	a)	Explain mechanical structure and components with working of SPM.	8
	b)	Draw schematic of AFM and explain the working of each component.	6
6.	a)	Describe the detail experimental procedure for the growth of nanomaterials by Molecular Beam Epitaxy technique.	8
	b)	Explain bright field image and dark field image with proper ray diagram in TEM.	6
7.	a)	Explain the conduction in metals, semiconductors in 3D (Bulk), 2D (Thin film) and low-dimensional systems.	8
	b)	Explain working of scanning electron microscope with an appropriate diagram.	6